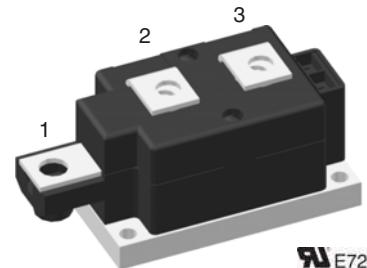
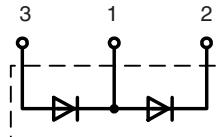


# High Power Diode Modules

**I<sub>FRMS</sub>** = 2x450 A  
**I<sub>FAVM</sub>** = 2x270 A  
**V<sub>RRM</sub>** = 1200-2200 V

V <sub>RSM</sub> V	V <sub>RRM</sub> V	Type
1300	1200	MDD 255-12N1
1500	1400	MDD 255-14N1
1700	1600	MDD 255-16N1
1900	1800	MDD 255-18N1
2100	2000	MDD 255-20N1
2300	2200	MDD 255-22N1



E72873

Symbol	Conditions	Maximum Ratings		
I <sub>FRMS</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	450	A	
I <sub>FAVM</sub>	T <sub>C</sub> = 100°C; 180° sine	270	A	
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; V <sub>R</sub> = 0	9500 t = 10 ms (50 Hz) 10200 t = 8.3 ms (60 Hz)	A	
	T <sub>VJ</sub> = T <sub>VJM</sub> V <sub>R</sub> = 0	8400 t = 10 ms (50 Hz) 9000 t = 8.3 ms (60 Hz)	A	
$\int i^2 dt$	T <sub>VJ</sub> = 45°C V <sub>R</sub> = 0	451 000 t = 10 ms (50 Hz) 437 000 t = 8.3 ms (60 Hz)	A <sup>2</sup> s	
	T <sub>VJ</sub> = T <sub>VJM</sub> V <sub>R</sub> = 0	353 000 t = 10 ms (50 Hz) 340 000 t = 8.3 ms (60 Hz)	A <sup>2</sup> s	
T <sub>VJ</sub>		-40...+150	°C	
T <sub>VJM</sub>		150	°C	
T <sub>stg</sub>		-40...+125	°C	
V <sub>ISOL</sub>	50/60 Hz, RMS I <sub>ISOL</sub> ≤ 1 mA	t = 1 min 3000 t = 1 s 3600	V~	
M <sub>d</sub>	Mounting torque (M6) Terminal connection torque (M8)	4.5-7/40-62 Nm/lb.in. 11-13/97-115 Nm/lb.in.		
Weight	Typical including screws	750	g	

Symbol	Conditions	Characteristic Values		
I <sub>RRM</sub>	T <sub>VJ</sub> = T <sub>VJM</sub> ; V <sub>R</sub> = V <sub>RRM</sub>	30	mA	
V <sub>F</sub>	I <sub>F</sub> = 600 A; T <sub>VJ</sub> = 25°C	1.4	V	
V <sub>TO</sub>	For power-loss calculations only	0.8	V	
r <sub>T</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	0.6	mΩ	
R <sub>thJC</sub>	per diode; DC current	0.140	K/W	
R <sub>thJK</sub>	per module	0.07	K/W	
	per diode; DC current	0.18	K/W	
	per module	0.09	K/W	
Q <sub>S</sub>	T <sub>VJ</sub> = 125°C; I <sub>F</sub> = 400 A; -di/dt = 50 A/μs	700	μC	
I <sub>RM</sub>		260	A	
d <sub>S</sub>	Creeping distance on surface	12.7	mm	
d <sub>A</sub>	Creepage distance in air	9.6	mm	
a	Maximum allowable acceleration	50	m/s <sup>2</sup>	

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

## Features

- International standard package
- Direct copper bonded Al<sub>2</sub>O<sub>3</sub>-ceramic with copper base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered E 72873

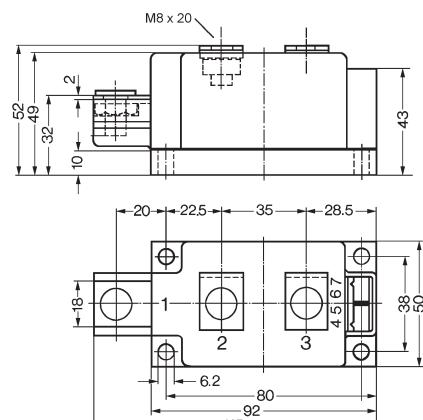
## Applications

- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

## Advantages

- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

## Dimensions in mm (1 mm = 0.0394")



Optional accessories for modules  
Keyed Gate/Cathode twin plugs with wire length = 350 mm, gate = yellow, cathode = red  
Type ZY 180 L (L = Left for pin pair 4/5) UL 758, style 1385,  
Type ZY 180 R (R = Right for pin pair 6/7) CSA class 5851, guide 460-1-1

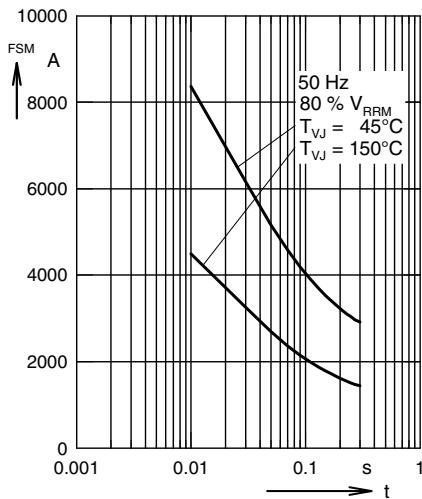


Fig. 1 Surge overload current  
 $I_{FSM}$ : Crest value,  $t$ : duration

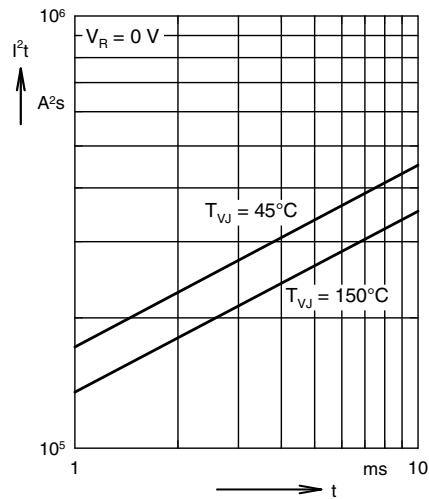


Fig. 2  $I^2t$  versus time (1-10 ms)

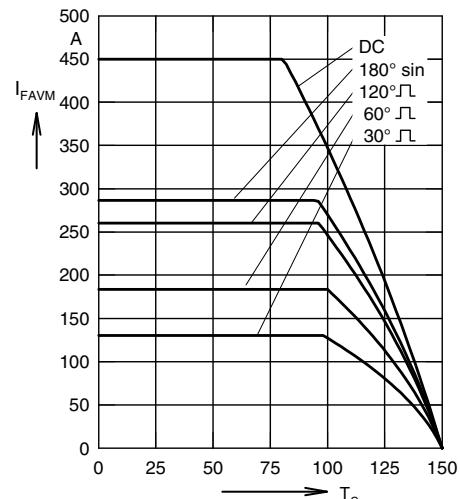


Fig. 3 Maximum forward current  
at case temperature

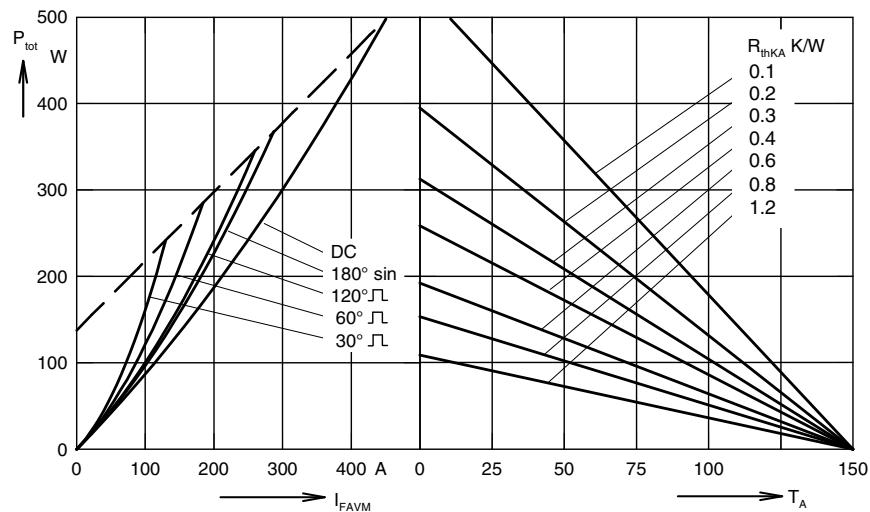


Fig. 4 Power dissipation vs. forward current and ambient temperature (per diode)

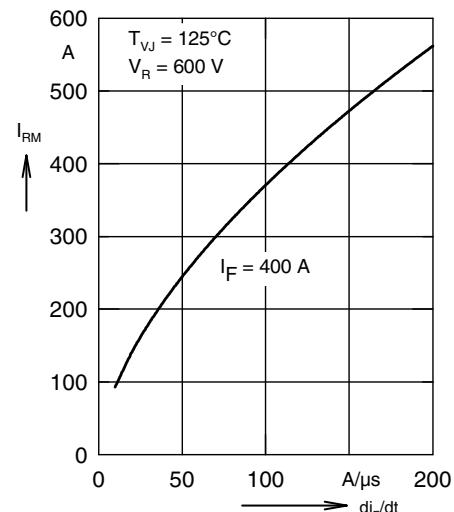


Fig. 5 Typ. peak reverse current  
 $I_{RM}$  versus  $-di_F/dt$

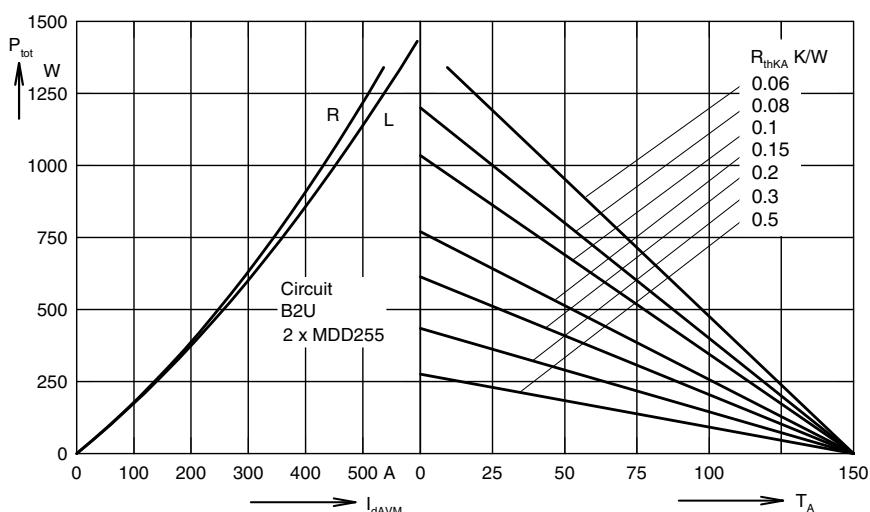


Fig. 6 Single phase rectifier bridge:Power dissipation vs. direct output current and ambient temperature  
R = resistive load, L = inductive load

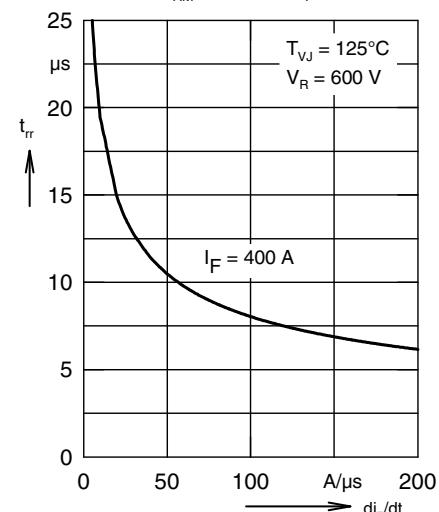


Fig. 7 Typ. recovery time  $t_{rr}$   
versus  $-di_F/dt$

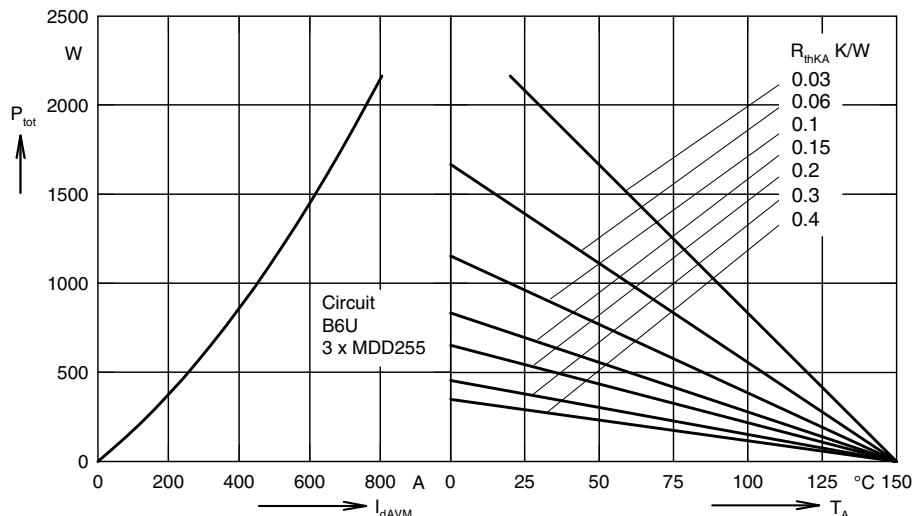


Fig. 8 Three phase rectifier bridge: Power dissipation vs. direct output current and ambient temperature

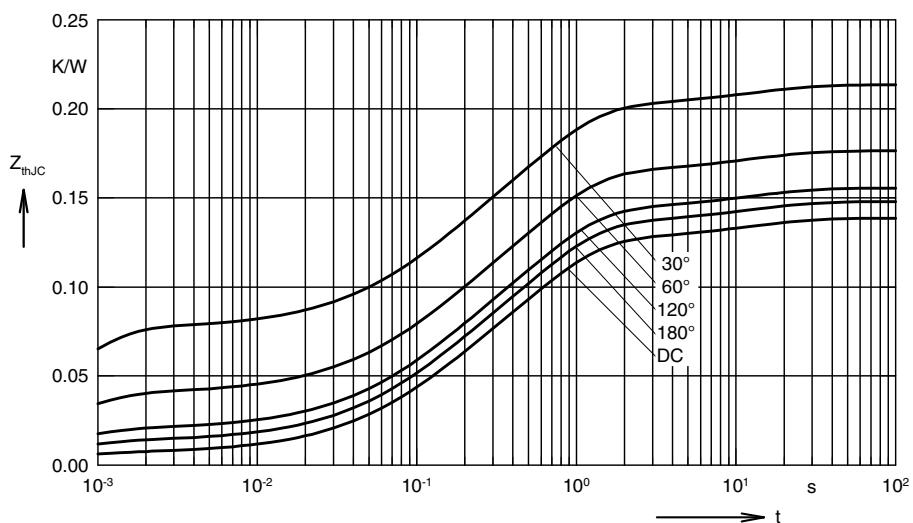


Fig. 9 Transient thermal impedance junction to case (per diode)

$R_{thJC}$  for various conduction angles d:

d	$R_{thJC}$ (K/W)
DC	0.139
180°	0.148
120°	0.156
60°	0.176
30°	0.214

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.0066	0.00054
2	0.0358	0.098
3	0.0831	0.54
4	0.0129	12

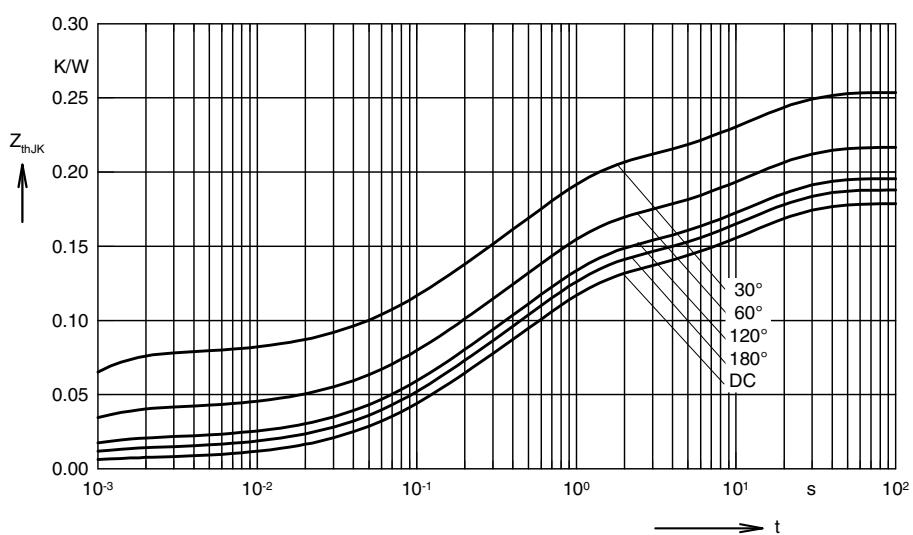


Fig. 10 Transient thermal impedance junction to heatsink (per diode)

$R_{thJK}$  for various conduction angles d:

d	$R_{thJK}$ (K/W)
DC	0.179
180°	0.188
120°	0.196
60°	0.216
30°	0.254

Constants for  $Z_{thJK}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.0066	0.00054
2	0.0358	0.098
3	0.0831	0.54
4	0.0129	12
5	0.04	12